## **General Purpose Transisters**

## **PNP Silicon**

## **Features**

• Pb-Free Packages are Available

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	$V_{CEO}$	-60	Vdc
Collector - Base Voltage	$V_{CBO}$	-60	Vdc
Emitter – Base Voltage	$V_{EBO}$	-5.0	Vdc
Collector Current – Continuous	Ic	-600	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) @T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) @T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

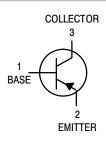
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- 1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



## ON Semiconductor®

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SOT-23 (TO-236AB) CASE 318 STYLE 6

#### **MARKING DIAGRAM**



2F = Device Code M = Date Code\* • = Pb-Free Package

(Note: Microdot may be in either location)
\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MMBT2907ALT1	SOT-23	3000 Tape & Reel
MMBT2907ALT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
MMBT2907ALT3	SOT-23	10,000 Tape & Reel
MMBT2907ALT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Charac	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS			•	•	•
Collector-Emitter Breakdown Voltage (Not	V <sub>(BR)CEO</sub>	-60	_	Vdc	
Collector – Base Breakdown Voltage (I <sub>C</sub> :	V <sub>(BR)CBO</sub>	-60	_	Vdc	
Emitter – Base Breakdown Voltage (I <sub>E</sub> =	V <sub>(BR)EBO</sub>	-5.0	_	Vdc	
Collector Cutoff Current (V <sub>CE</sub> = -30 Vdc,	$V_{EB(off)} = -0.5 \text{ Vdc}$	I <sub>CEX</sub>	-	-50	nAdc
Collector Cutoff Current $(V_{CB} = -50 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -50 \text{ Vdc}, I_E = 0, T_A = 125^{\circ}\text{C})$	I <sub>CBO</sub>	- -	-0.010 -10	μAdc	
Base Cutoff Current ( $V_{CE} = -30 \text{ Vdc}, V_{E}$	B(off) = -0.5  Vdc	I <sub>BL</sub>	_	-50	nAdc
ON CHARACTERISTICS					
DC Current Gain $ \begin{aligned} &(I_C = -0.1 \text{ mAdc, V}_{CE} = -10 \text{ Vdc}) \\ &(I_C = -1.0 \text{ mAdc, V}_{CE} = -10 \text{ Vdc}) \\ &(I_C = -10 \text{ mAdc, V}_{CE} = -10 \text{ Vdc}) \\ &(I_C = -150 \text{ mAdc, V}_{CE} = -10 \text{ Vdc}) \\ &(I_C = -500 \text{ mAdc, V}_{CE} = -10 \text{ Vdc}) \end{aligned} $	te 3)	h <sub>FE</sub>	75 100 100 100 50	- - 300 -	-
Collector – Emitter Saturation Voltage (Note 3) (I <sub>C</sub> = -150 mAdc, I <sub>B</sub> = -15 mAdc) (Note 3) (I <sub>C</sub> = -500 mAdc, I <sub>B</sub> = -50 mAdc)		V <sub>CE(sat)</sub>	- -	-0.4 -1.6	Vdc
Base – Emitter Saturation Voltage (Note In Circle 150 mAdc, $I_B = -15$ mAdc) ( $I_C = -500$ mAdc, $I_B = -50$ mAdc)	V <sub>BE(sat)</sub>	- -	-1.3 -2.6	Vdc	
SMALL-SIGNAL CHARACTERISTICS			•		1
Current-Gain - Bandwidth Product (Not f = 100 MHz)	f <sub>T</sub>	200	-	MHz	
Output Capacitance (V <sub>CB</sub> = -10 Vdc, I <sub>E</sub>	= 0, f = 1.0 MHz)	C <sub>obo</sub>	_	8.0	pF
Input Capacitance ( $V_{EB} = -2.0 \text{ Vdc}$ , $I_{C} =$	C <sub>ibo</sub>	_	30	1	
SWITCHING CHARACTERISTICS				<u> </u>	1
Turn-On Time		t <sub>on</sub>	_	45	
Delay Time	$(V_{CC} = -30 \text{ Vdc}, I_{C} = -150 \text{ mAdc}, I_{B_1} = -15 \text{ mAdc})$	t <sub>d</sub>	_	10	
Rise Time	13 111 (33)	t <sub>r</sub>	_	40	
Turn-Off Time		t <sub>off</sub>	_	100	- ns
Storage Time	$(V_{CC} = -6.0 \text{ Vdc}, I_{C} = -150 \text{ mAdc}, I_{B1} = I_{B2} = -15 \text{ mAdc})$	t <sub>s</sub>	-	80	
Fall Time	-61 -62	t <sub>f</sub>	_	30	1

<sup>3.</sup> Pulse Test: Pulse Width  $\leq 300 \,\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

<sup>4.</sup>  $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

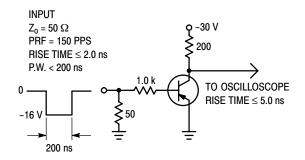


Figure 1. Delay and Rise Time Test Circuit

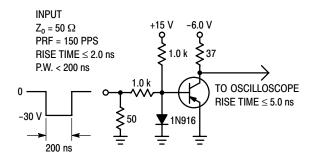


Figure 2. Storage and Fall Time Test Circuit

## **TYPICAL CHARACTERISTICS**

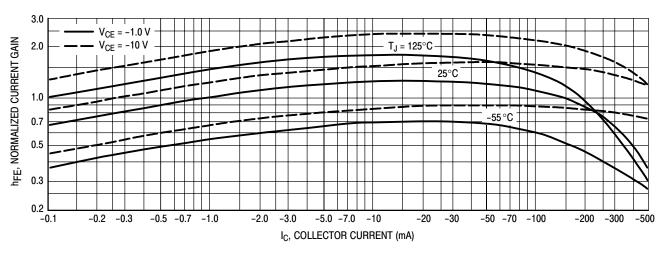


Figure 3. DC Current Gain

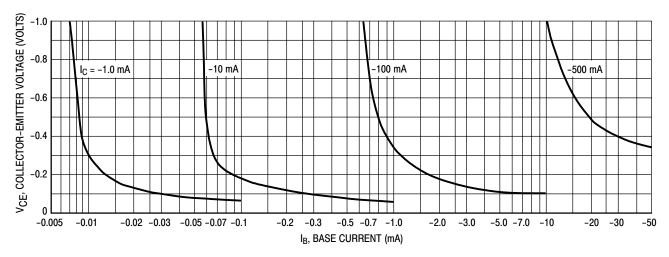


Figure 4. Collector Saturation Region

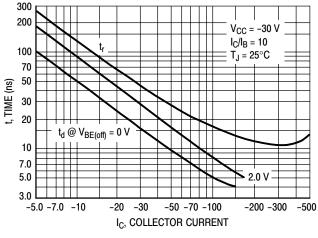


Figure 5. Turn-On Time

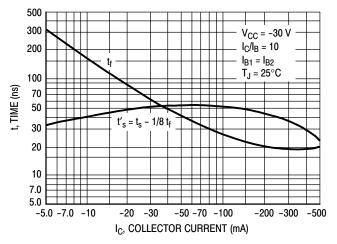
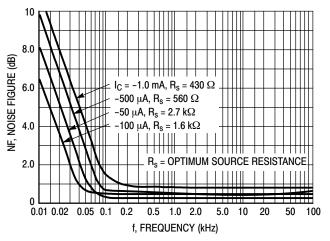


Figure 6. Turn-Off Time

# TYPICAL SMALL-SIGNAL Characteristics NOISE FIGURE

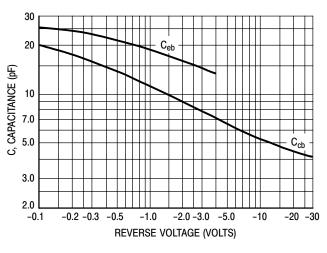
 $V_{CE}$  = 10 Vdc,  $T_A$  = 25°C



8.0 NF, NOISE FIGURE (dB) 6.0 I<sub>C</sub> = -50 μA -100 μA -500 μA 4.0 2.0 100 200 2.0 k 5.0 k 10 k 20 k 50 k 50 1.0 k R<sub>s</sub>, SOURCE RESISTANCE (OHMS)

Figure 7. Frequency Effects

Figure 8. Source Resistance Effects



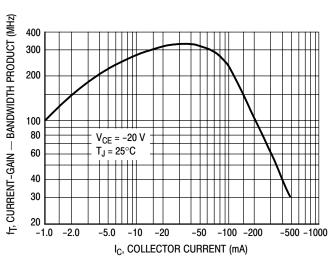
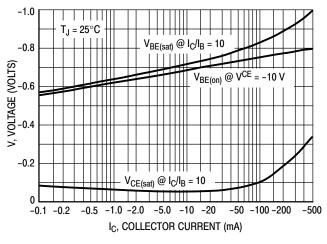


Figure 9. Capacitances

Figure 10. Current-Gain - Bandwidth Product



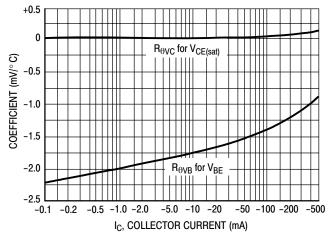
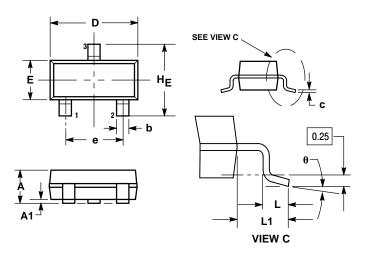


Figure 11. "On" Voltage

Figure 12. Temperature Coefficients

## PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

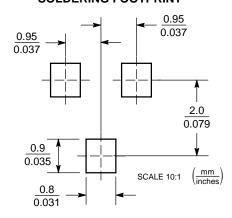
  3. MAXIMUM LEAD THICKNESS INCLUDES
  LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL. 4. 318-01 THRU -07 AND -09 OBSOLETE,
- NEW STANDARD 318-08.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6: PIN 1. BASE

- **EMITTER**
- 3 COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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